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Dimensional crossover and flux pinning of decoupled Cu₅₀Ni₅₀/Nb multilayers

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The behaviors of superconducting transition temperature T_c and upper critical field H_{c2} as a function of different superconductor thicknesses have been investigated in Cu₅₀Ni₅₀/Nb trilayers and multilayers. We deduced superconductor critical thickness, below which superconductivity vanishes, by analyzing the data in terms of proximity theory. The temperature dependence of H_{c2} measurement reveals the spatial dimensional crossover and the flux pinning mechanism in the superconductor. A strong pair-breaking effect was observed in the weak ferromagnetic Cu₅₀Ni₅₀ layers from both measurements. We attribute our observation to the high interface transparency between Cu₅₀Ni₅₀ and Nb. © 2008 American Institute of Physics. [DOI: [10.1063/1.2829607](https://doi.org/10.1063/1.2829607)]

An artificial ferromagnet/superconductor (F/S) layered system is a suitable candidate for studying the coexistence of superconductivity and ferromagnetism by proximity effect. The Cooper pairs tend to leak out and remain superconducting in the adjacent F region. On the other hand, the electrons in the F region induce unequal spin population in the superconductor. They influence each other via the penetration of electrons through their common interface. The superconducting wave function not only decays in F , but also oscillates in a region of characteristic length ξ_F . The weak ferromagnetic layer of Cu₅₀Ni₅₀ is essential in achieving the appropriate exchange energy in a suitable window of the experimental phase space by a long magnetic coherence length, ξ_F . Various unusual phenomena occur in the CuNi/Nb system due to the oscillation of the S pairing wave function in F (see Refs. 1 and 2 for recent reviews). However, the quality of interfaces is one of the most important key factors.³ In the present paper, we find that the properties of the interfaces strongly influence the temperature dependence of upper critical field H_{c2} and the thickness dependence of T_c . Nb is chosen as the superconductor and the Cu₅₀Ni₅₀ alloy as weak ferromagnet in studying the thickness dependence of T_c , the spatial dimensional crossover, and the flux pinning mechanism. Both measurements agree that the transparency of the Cu₅₀Ni₅₀/Nb interface is rather high. A comparison between weak and strong ferromagnetic films is given.

Several series of Cu₅₀Ni₅₀/Nb trilayer and multilayer samples were fabricated on Si(100) substrates using a sputtering system with a sample holder which allowed us to make 12 samples in the same run to obtain comparable quality samples for different F and S layer thicknesses. The detailed deposition conditions used for the present samples were similar to those described elsewhere.^{4,5} The measurements of the magnetic moments were performed by a commercial superconducting quantum interference device magnetometer. In our sputtered Cu₅₀Ni₅₀ alloy, the magnetic moment was about 0.1 Bohr magneton per atom and the Curie temperature was about 100 K. In order to investigate the proximity effect between Nb and Cu₅₀Ni₅₀ in a decoupled regime, we will mainly discuss the series of samples as follows: (1) Cu₅₀Ni₅₀/Nb(d_S)/Cu₅₀Ni₅₀ trilayers with Cu₅₀Ni₅₀ thickness fixed at 50 nm and (2) Cu₅₀Ni₅₀/Nb multilayers denoted as (Cu₅₀Ni₅₀/Nb(d_S))₆/Cu₅₀Ni₅₀ with Cu₅₀Ni₅₀ thickness fixed at 20 nm. The thickness of the Nb layer for both systems varied. The critical temperature T_c and the critical field H_{c2} as a function of temperature were resistively measured in a ⁴He cryostat on structured samples of 5 mm long and 1 mm wide.

T_c was determined by resistance measurements and was taken at 90% of the resistance just above the transition. The T_c for Cu₅₀Ni₅₀/Nb(d_S)/Cu₅₀Ni₅₀ trilayers as a function of d_{Nb} are shown in Fig. 1. With decreasing d_{Nb} , T_c exhibited a monotonically rapid reduction down to a critical thickness d_{crit} . The superconducting transition with $d_{Nb} < d_{crit}$ was not recorded at 1.7 K, the base temperature of our cryostat. The

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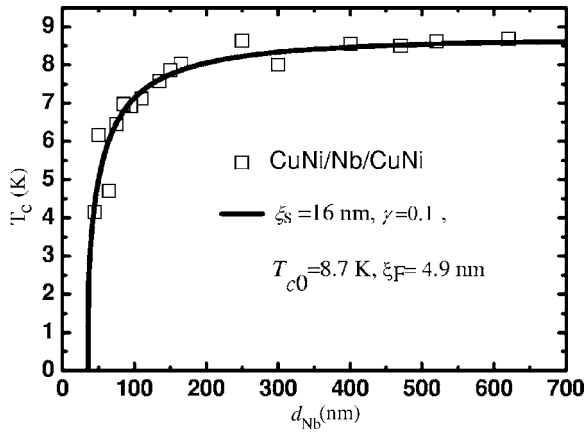


FIG. 1. Superconducting critical temperatures for $\text{Cu}_{50}\text{Ni}_{50}/\text{Nb}/\text{Cu}_{50}\text{Ni}_{50}$ trilayers as a function of d_{Nb} . The solid line is obtained from the theoretical fitting with parameters $\xi_S=16$ nm, $\gamma=0.1$, and $T_{c0}=8.7$ K.

decrease in T_c resulted from the suppression of the superconducting wave function at the F/S interface by the pair-breaking effect. We analyzed the behavior of $T_c(d_S)$ in the framework of the theoretical model developed by Radvoić *et al.*⁶ In the single-mode approximation, the reduced critical temperature of our trilayers is associated with the pair-breaking effect from the following equations;⁶ $\ln(T_c/T_{c0}) = \Psi(1/2) - \text{Re} \Psi[(1/2) + (\rho^*/T_c)T_{c0}]$, where $\text{Re} \Psi$ represents the real part of the digamma function, T_{c0} is the bulk critical temperature, and ρ^* is the effective pair-breaking parameter. The high interface transmission of boundary condition to evaluate T_c as a function of d_S is given by⁷

$$K_S d_S \tan\left(\frac{K_S d_S}{2}\right) = 2(1+i)\gamma \frac{d_S}{\xi_S} \\ \times \tanh\left[2(1+i)\frac{d_F}{\xi_F}\right], \\ \text{with } \gamma = \frac{\rho_S \xi_S}{\rho_F \xi_F}, \quad \xi_F = \sqrt{\frac{4\hbar D_F}{I_0}}.$$

Here, $\rho_{S,F}$ are the low-temperature resistivities of S and F , D_F is the diffusion coefficient, and I_0 is the spin splitting energy of F . The simple physical meaning of γ is the strength of the proximity effect between the F and S metals. The diffusion coefficient D_F is related to the electron mean free path ℓ_F , the Fermi velocity v_F , and the electronic specific heat coefficients γ_F by⁸ $D_F = v_F \ell_F / 3 = (1/3) \gamma_F \rho_F \times (\pi k_B / e)^2$.

In this way, using $\gamma(\text{Cu}_{50}\text{Ni}_{50}) \approx 4.2 \times 10^{-3}$ J/K² mole,⁹ $\rho_F \approx 61 \mu\Omega$ cm, and $I_0 \approx 6$ meV, the $\text{Cu}_{50}\text{Ni}_{50}$ coherence length is evaluated to be $\xi_F = 4.9$ nm. The result of the theoretical simulations obtained for the trilayer system with $\gamma = 0.1$, $\xi_S = 16$ nm, and $T_{c0} = 8.7$ K is shown as the solid line in Fig. 1. By extrapolating the fit to $T_c = 0$, the critical thickness is $d_{\text{crit}}(\text{Cu}_{50}\text{Ni}_{50}) = 35$ nm. For the purpose of comparison, the critical thicknesses were about 30 and 34 nm for $\text{Co}/\text{Nb}/\text{Co}$ (Ref. 10) and $\text{Fe}/\text{Nb}/\text{Fe}$ (Ref. 11) trilayers, respectively. It is found that the critical thickness is not smaller than those for the strong ferromagnet. For weak magnetic $V_{1-x}\text{Fe}_x$ system,

the large critical thicknesses have also been observed.³ We will now argue that this large thickness is due to the large interface transparency T_r .

Aarts *et al.*³ proposed that the behavior of the critical thickness for the $F/S/F$ case is a function of the parameters γ and γ_b . The parameter γ_b describes the quality of the interface barrier. When γ is small as in our case, the ‘‘proximity leak’’ is large. It requires a low barrier (high T_r , small γ_b) to increase the critical thickness. Potensa and Marrows¹² reported $\gamma_b = 0.6$, and Fominov *et al.* obtained a value of 0.3 when fitting the CuNi/Nb bilayer data.¹³ These values for CuNi/Nb were much smaller than $\gamma_b = 1.6$ for Co/Nb system obtained from direct interface resistance measurements.¹⁴ Both measurements agree that the transparency of a CuNi/Nb interface is rather high. This conclusion is in agreement with the critical field H_{c2} data presented in this paper.

Another parameter to investigate the coupling phenomenon is the upper critical field H_{c2} , which gives the information on the coherence length and the dimensionality since H_{c2} reveals the role of the pair-breaking effect. From the Ginzburg-Landau (GL) theory, the perpendicular critical magnetic field for a superconducting film with thickness d_S shows linear temperature dependence, $H_{c2\perp} = [\phi_0 / 2\pi \xi_{\parallel}^2(0)] \times [1 - (T/T_c)]$.

Here, ϕ_0 is the flux quantum, and $\xi_{\parallel}(0)$ ($\xi_{\perp}(0)$) is the zero temperature value of the GL coherence length parallel (perpendicular) to the sample plane. The behavior of the parallel critical field $H_{c2\parallel}(T)$ can be described by a similar expression where ξ_{\parallel}^2 is replaced $\xi_{\parallel}(0) \xi_{\perp}(0)$. In the three-dimensional (3D) regime, the temperature dependence of $H_{c2\parallel}(T)$ is described by $H_{c2\parallel} = [\phi_0 / 2\pi \xi_{\parallel}(0) \xi_{\perp}(0)] [1 - (T/T_c)]$, while in the two-dimensional (2D) regime, the perpendicular coherence length ξ_{\perp} is larger than the thickness of the films, and $H_{c2\parallel}(T)$ is described by Tinkham’s expression¹⁵

$$H_{c2\parallel} = \frac{\sqrt{12} \phi_0}{2\pi \xi_{\parallel}(0) d_S} \sqrt{\left(1 - \frac{T}{T_c}\right)}.$$

Samples

with

$(\text{Cu}_{50}\text{Ni}_{50}(20 \text{ nm})/\text{Nb}(d_S))_6/\text{Cu}_{50}\text{Ni}_{50}(20 \text{ nm})$, with d_S ranging from 20 to 600 nm, were measured. Figure 2 shows the temperature dependence of the $H_{c2\parallel}$ and $H_{c2\perp}$ for $d_{\text{Nb}} = 140$, and $H_{c2\parallel}$ for $d_{\text{Nb}} = 160$ and 180 nm. Data points for two samples with bigger d_{Nb} are relatively shifted by 0.05 in the x axis for clarity. The solid lines are theoretical curves by the GL relation. The $H_{c2\perp}$ follows a linear behavior for all thicknesses of Nb. It can be clearly seen that a gradual transition occurs from 2D to 3D behaviors as d_S increases from 140 to 180 nm, i.e., from a square-root behavior to a linear relation for the $H_{c2\parallel}$. The extrapolation yields a superconductor coherence length $\xi_{\text{GL}}(0) = 12$ nm from the function $\xi_{\text{GL}}(0) = \sqrt{\phi_0 / 2\pi S T}$ where $S = -dH_{c2} / dT$.

For comparison, the dimension crossover is 100–140 nm for Nb/Fe (Ref. 11) and 145–185 nm for Nb/Co ,¹⁶ confirming that the large crossover thickness is related to the strong pair-breaking effect since $I_0(\text{Co}) > I_0(\text{Fe})$. The large dimension crossover thickness for $\text{Cu}_{50}\text{Ni}_{50}$ can be attributed to the high interface transparency

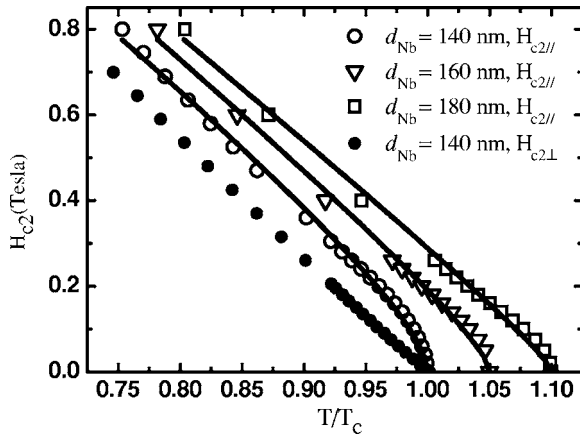


FIG. 2. Temperature dependence of the perpendicular (filled circles) upper critical fields for $\text{Cu}_{50}\text{Ni}_{50}/\text{Nb}$ multilayers with $d_{\text{Nb}}=140$ nm, and parallel fields (open circles, triangles, and squares) with $d_{\text{Nb}}=140, 160,$ and 180 nm. Data for the $d_{\text{Nb}}=160$ and 180 nm are shifted to the right by $T/T_c=0.05$ and 0.1 , respectively, for clarity. The lines are least-square fit to describe the 3D to 2D crossover using the Ginzburg-Landau relation.

even in the weak ferromagnetic system. Angrisani Armenio *et al.* have observed that the temperature, where the 2D to 3D crossover occurred, moved toward a lower value for high interface transparency from the temperature dependent H_{c2} measurement with $d_{\text{CuNi}}=d_{\text{Nb}}=30$ nm.¹⁷ Thus, the influence due to the barrier properties on the dimensionality, which is decided from the thickness of the S layer, also provides unambiguous evidence.

The temperature dependence of H_{c2} contains the information of the flux pinning mechanism in the superconductor, which can be revealed by analyzing the activation energy of the thermally assisted flux flow (TAFF). TAFF can be detected through the resistivity versus temperature curves for different applied fields. The activation energy U_0 is estimated by the Arrhenius law,¹⁸ $\rho=\rho_0 \exp(-U_0/k_B T)$, where ρ_0 is a field-independent preexponential factor. For comparison, a monolayer of 240 nm Nb film and a 2D ($\text{Cu}_{50}\text{Ni}_{50}/\text{Nb}$) multilayer with the same total Nb thickness were prepared. Figure 3 shows the activation energy of flux flows versus applied field H . The difference of activation energy between the parallel and perpendicular fields was relatively small in the pure Nb film, while for the $d_{\text{Nb}}=40$ nm multilayer, the U_0 for parallel field was four times the value for perpendicular field, which implied an easier TAFF due to vortex decoupling across $\text{Cu}_{50}\text{Ni}_{50}$ interlayers in the 2D system. In the $\text{MgB}_2/\text{Mg}_2\text{Si}$ multilayer, U_0 for parallel field was significantly larger than the pure MgB_2 film due to the vortices trapping in the nonsuperconducting Mg_2Si layers.¹⁹ Thus, in Fig. 3, the U_0 for parallel field showed the same level of flux pinning between our $\text{Cu}_{50}\text{Ni}_{50}/\text{Nb}$ multilayer, and pure Nb can be attributed to the high interface transparency between Nb and $\text{Cu}_{50}\text{Ni}_{50}$. Therefore, the H_{c2} measurement provides a lot of useful information to study the proximity effect in F/S system.

In summary, experiments on the proximity effect in the decoupled $\text{Cu}_{50}\text{Ni}_{50}/\text{Nb}$ layered structure have been per-

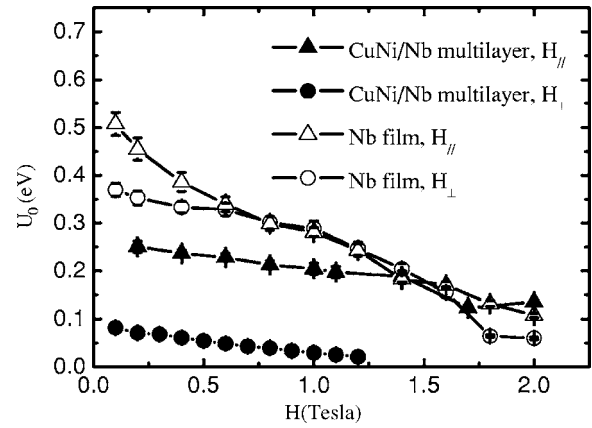


FIG. 3. Activation energy U_0 of flux flow versus parallel and perpendicular applied field for $(\text{Cu}_{50}\text{Ni}_{50}/\text{Nb})_6/\text{Cu}_{50}\text{Ni}_{50}$ multilayer with $d_{\text{Nb}}=40$ nm and monolayer Nb with $d_{\text{Nb}}=240$ nm. Open symbols are for monolayer and solid symbols for multilayers. Data for a parallel field are in triangles and those for a perpendicular field in circles.

formed by measurements of the thickness dependence of the superconducting transition temperature. The critical thickness and the strength of proximity effect have been derived from analyzing data within the proximity effect theory. We also studied the dimensionality crossover by the temperature dependent H_{c2} measurement and the flux pinning mechanism. The strong pairing-breaking effect observed in the weak ferromagnetic layer, which resulted in a strong influence on the critical thickness and the dimensional crossover, was due to the high interface transparency between $\text{Cu}_{50}\text{Ni}_{50}$ and Nb.

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